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S2A ~ S2M

SURFACE MOUNT RECTIFIERS

PRV : 50 - 1000 Volts
Io : 2.0 Ampere

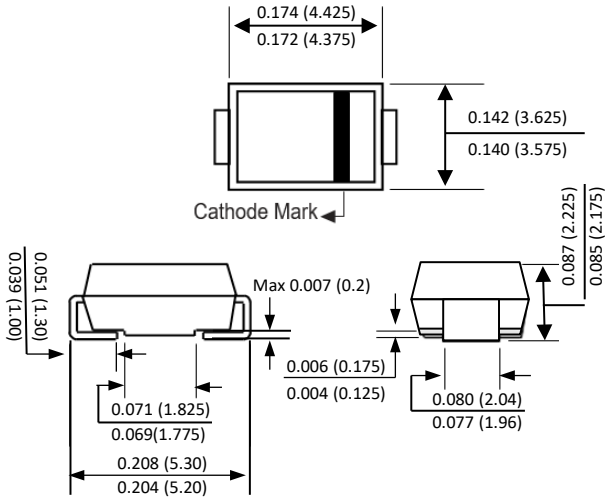
FEATURES :

* Glass passivate junction chip
* High current capability
* High surge current capability
* High reliability
* Low reverse current
* Low forward voltage drop
* Pb / RoHS Free

MECHANICAL DATA :

* Case : SMB Molded plastic
* Epoxy : UL94V-0 rate flame retardant
* Lead : Lead Formed for Surface Mount
* Polarity : Indicated by cathode band
* Mounting position : Any
* Weight : 0.093 gram

SMB (DO-214AA)



Dimensions in inches and (millimeters)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating at 25 °C ambient temperature unless otherwise specified.
Single phase, half wave, 60 Hz, resistive or inductive load.
For capacitive load, derate current by 20%.

RATING	SYMBOL	S2A	S2B	S2D	S2G	S2J	S2K	S2M	UNIT
Maximum Repetitive Peak Reverse Voltage	V_{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	V_{RMS}	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	V_{DC}	50	100	200	400	600	800	1000	V
Maximum Average Forward Current at T_L = 110 °C	$I_{F(AV)}$	2.0							A
Peak Forward Surge Current 8.3ms Single half sine wave Superimposed on rated load (JEDEC Method) T_L = 100 °C	I_{FSM}	60							A
Maximum Instantaneous Forward Voltage at I_F = 2.0 A.	V_F	1.1							V
Maximum DC Reverse Current Ta = 25 °C	I_R	5.0							μA
at rated DC Blocking Voltage Ta = 125 °C	$I_{R(H)}$	200							μA
Typical thermal resistance	$R_{\theta JL}$	16							°C/W
Typical Junction Capacitance (Note 1)	C_J	30							pF
Junction Temperature Range	T_J	- 55 to + 150							°C
Storage Temperature Range	T_{STG}	- 55 to + 150							°C

Notes :

(1) Measured at 1.0 MHz and applied reverse voltage of 4.0 VDC

RATING AND CHARACTERISTIC CURVES (S2A - S2M)

FIG.1 - DERATING CURVE FOR OUTPUT RECTIFIED CURRENT

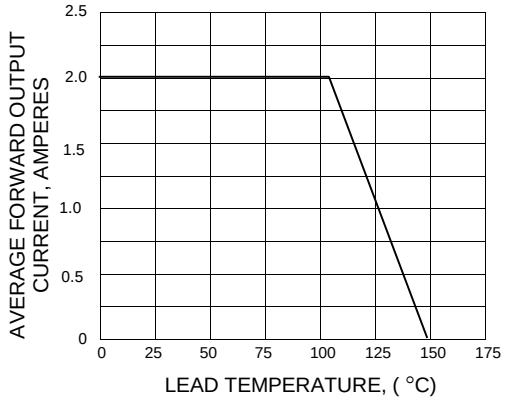


FIG.2 - MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

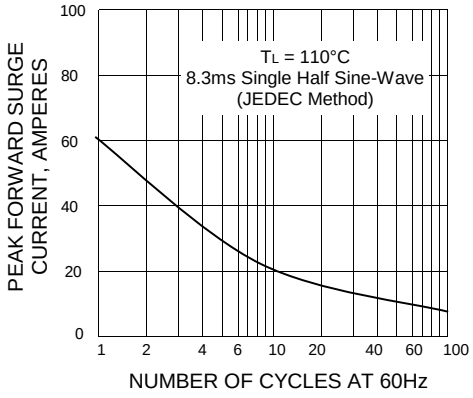


FIG.3 - TYPICAL FORWARD CHARACTERISTICS

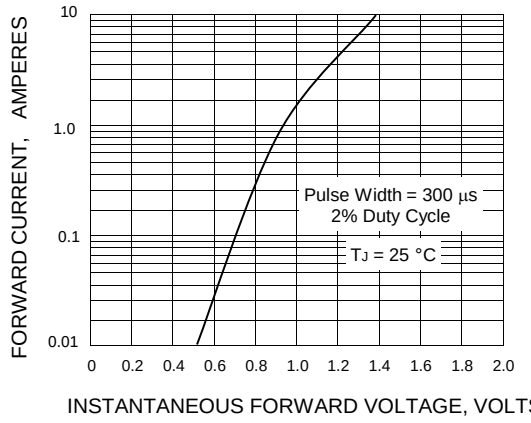


FIG.4 - TYPICAL REVERSE CHARACTERISTICS

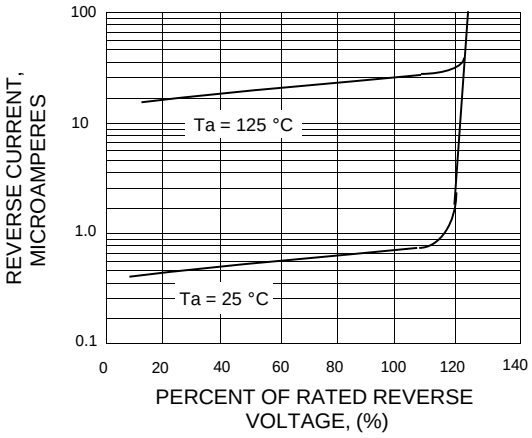


FIG. 5 – TYPICAL JUNCTION CAPACITANCE

